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	Subclass
Class	ISSUE CLASSIFICATION

PATENT NUMBER

U.S. REISSUE Patent Application

O.I.P.E.	O.G. PUBLICATION DATE	REISSUE PATENT DATE
SCANNED HKM13 Q.A.		

APPLICATION NO. 09/986997	CONT/PRIOR D F	CLASS 438	SUBCLASS 46	ART UNIT 2823	EXAMINER S. P. K.
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APPLICANTS

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TITLE

Method for fabricating semiconductor device having group III nitride

PTO-2040
12/93

<input type="checkbox"/> SURRENDER OF ORIGINAL PATENT	(Ex. Initials)	ORIGINAL PATENT NUMBER _____
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ISSUING CLASSIFICATION

ORIGINAL		CROSS REFERENCE(S)					
CLASS	SUBCLASS	CLASS	SUBCLASS (ONE SUBCLASS PER BLOCK)				
INTERNATIONAL CLASSIFICATION							
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<input type="checkbox"/> TERMINAL DISCLAIMER	DRAWINGS			CLAIMS ALLOWED	
	Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
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<input type="checkbox"/> The term of this patent shall not extend beyond the expiration date of U.S Patent No. _____				ISSUE FEE	
<input type="checkbox"/> The terminal ____ months of this patent have been disclaimed.				Amount Due	Date Paid
FINAL SPRE REVIEW				ISSUE BATCH NUMBER	
(INITIALS)	(Legal Instruments Examiner)			(Date)	

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